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Low-power D-type transparent latch; 3-state

Rev. 6 — 4 July 2012

Product data sheet

1. General description

The 74AUP1G373 provides the single D-type transparent latch with 3-state output. While the latch-enable (LE) input is high, the Q output follows the data (D) input. When pin LE is LOW, the latch stores the information that was present at the D-input one set-up time preceding the HIGH-to-LOW transition of pin LE. When pin \overrightarrow{OE} is LOW, the contents of the latch is available at the (Q) output. When pin \overrightarrow{OE} is HIGH, the output goes to the high-impedance OFF-state. Operation of input pin \overrightarrow{OE} does not affect the state of the latch.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - ◆ JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - ◆ JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



Low-power D-type transparent latch; 3-state

3. Ordering information

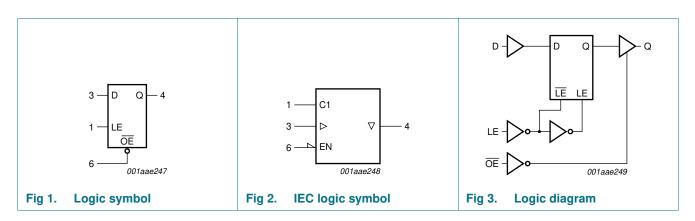
Table 1. Orderin	g information			
Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G373GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363
74AUP1G373GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886
74AUP1G373GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891
74AUP1G373GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115
74AUP1G373GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202

4. Marking

Table 2. Marking	
Type number	Marking code ^[1]
74AUP1G373GW	aW
74AUP1G373GM	aW
74AUP1G373GF	aW
74AUP1G373GN	aW
74AUP1G373GS	aW

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

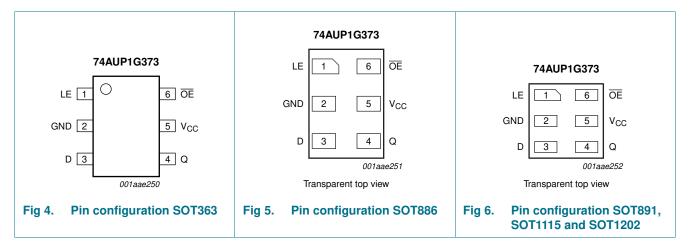


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Low-power D-type transparent latch; 3-state

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
LE	1	latch enable input (active HIGH)
GND	2	ground (0 V)
D	3	data input
Q	4	latch output
V _{CC}	5	supply voltage
OE	6	output enable input (active LOW)

7. Functional description

Table 4.Function table

Operating modes	Input			Internal latch	Output
	OE	LE	D		Q
Enable and read register (transparent	L	Н	L	L	L
mode)	L	Н	Н	Н	Н
Latch and read register	L	L	Ι	L	L
	L	L	h	Н	Н
Latch register and disable outputs	Н	Х	Х	Х	Z

[1] H = HIGH voltage level;

h = HIGH voltage level one setup time prior to the HIGH-to-LOW LE transition;

L = LOW voltage level;

I = LOW voltage level one setup time prior to the HIGH-to-LOW LE transition;

X = Don't care;

Z = high-impedance OFF-state.

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Low-power D-type transparent latch; 3-state

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

				(0	/
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage		<u>1</u> –0.5	+4.6	V
I _{OK}	output clamping current	$V_{\rm O} < 0 \ V$	-50	-	mA
Vo	output voltage	Active mode and Power-down mode	<u>1</u> –0.5	+4.6	V
lo	output current	$V_{O} = 0 V$ to V_{CC}	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[2] _	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

For XSON6 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6. **Recommended operating conditions** Symbol Conditions Min Unit Parameter Max supply voltage 0.8 3.6 V_{CC} ٧ 3.6 Vı input voltage 0 ٧ Vo output voltage Active mode 0 V_{CC} V Power-down mode; $V_{CC} = 0 V$ 0 3.6 ٧ Tamb ambient temperature -40 +125 °C $\Delta t / \Delta V$ input transition rise and fall rate V_{CC} = 0.8 V to 3.6 V _ 200 ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70 \times V_{CC}$	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL} L	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30\times V_{CC}$	V
		V _{CC} = 0.9 V to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
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Product d	lata abaat	Pov. 6 4 July 2012				4 of 2

74AUP1G373

Low-power D-type transparent latch; 3-state

At recommended operating conditions; voltages are referenced to GND (ground = 0 V). Symbol Parameter Conditions Max Unit Min Тур HIGH-level output voltage VOH $V_{I} = V_{IH} \text{ or } V_{II}$ $V_{CC} - 0.1$ V $I_{O} = -20 \ \mu A$; $V_{CC} = 0.8 \ V$ to 3.6 V -_ $I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ $0.75 \times V_{CC}$ -V - $I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ 1.11 ٧ - $I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ 1.32 V _ _ $I_{O} = -2.3 \text{ mA}; V_{OO} = 2.3 \text{ V}$ 2.05 ٧ _ _ $I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 1.9 ٧ --V $I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ 2.72 _ _ $I_{O} = -4.0 \text{ mA}; V_{OO} = 3.0 \text{ V}$ 2.6 ٧ _ _ VOL LOW-level output voltage $V_I = V_{IH} \text{ or } V_{IL}$ 0.1 v $I_{O} = 20 \ \mu A$; $V_{CC} = 0.8 \ V$ to 3.6 V -_ $I_{O} = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ $0.3 \times V_{CC}$ ٧ _ _ $I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ 0.31 ٧ -v I_O = 1.9 mA; V_{CC} = 1.65 V -0.31 - $I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 0.31 ٧ _ - $I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 0.44 V -- $I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ 0.31 V _ _ $I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ 0.44 ٧ _ _ input leakage current $V_1 = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V ±0.1 I_L μA -- $V_{I} = V_{IH}$ or V_{IL} ; $V_{O} = 0$ V to 3.6 V; OFF-state output current loz _ _ ±0.1 μΑ $V_{CC} = 0 V \text{ to } 3.6 V$ IOFF power-off leakage current V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V _ _ ±0.2 μA additional power-off $V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V};$ ±0.2 ΔI_{OFF} -_ μΑ $V_{CC} = 0$ V to 0.2 V leakage current $V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ supply current 0.5 Icc _ μΑ $V_{CC} = 0.8 V$ to 3.6 V <u>[1]</u> _ $V_{I} = V_{CC} - 0.6 V; I_{O} = 0 A;$ ΔI_{CC} additional supply current 40 μA - $V_{CC} = 3.3 V$ Cı $V_{CC} = 0$ V to 3.6 V; $V_I = GND$ or V_{CC} input capacitance 0.8 pF --Co output enabled; V_O = GND; V_{CC} = 0 V 1.7 pF output capacitance _ _ output disabled; $V_{CC} = 0$ V to 3.6 V; 1.5 pF _ _ $V_{O} = GND \text{ or } V_{CC}$ $T_{amb} = -40 \circ C \text{ to } +85 \circ C$ VIH HIGH-level input voltage $V_{CC} = 0.8 V$ $0.70 \times V_{CC}$ -V _ $V_{CC} = 0.9 \text{ V}$ to 1.95 V $0.65 \times V_{CC}$ -٧ -V_{CC} = 2.3 V to 2.7 V ٧ 1.6 - $V_{CC} = 3.0 V \text{ to } 3.6 V$ V 2.0 _ _ LOW-level input voltage $V_{CC} = 0.8 V$ VII - $0.30 \times V_{CC}$ V -V_{CC} = 0.9 V to 1.95 V $0.35 \times V_{CC}$ V -- $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ V 0.7 _ _ $V_{CC} = 3.0 \text{ V}$ to 3.6 V ٧ 0.9 _ _

Table 7. Static characteristics ... continued

Product data sheet

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Low-power D-type transparent latch; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{он}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu A;$ V_{CC} = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7\times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.33	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V
l _l	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.5	μA
I _{OZ}	OFF-state output current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 V \text{ to } 3.6 V; \\ V_{CC} = 0 V \text{ to } 3.6 V \end{array}$	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI_{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \; A; \\ V_{CC} = 0.8 \; V \; to \; 3.6 \; V \end{array}$	-	-	0.9	μA
Δl _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	<u>[1]</u> -	-	50	μA
T _{amb} = –	40 °C to +125 °C					
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	$0.75 imes V_{CC}$	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.70 imes V_{CC}$	-	-	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	۷
V _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.25\times V_{CC}$	۷
		V _{CC} = 0.9 V to 1.95 V	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$	-	-	0.7	V
		V_{CC} = 3.0 V to 3.6 V	-	-	0.9	V

Table 7. Static characteristics ...continued

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Low-power D-type transparent latch; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OH}	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		I_O = –20 $\mu A;V_{CC}$ = 0.8 V to 3.6 V	V _{CC} – 0.11	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.6 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	0.93	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.17	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.77	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.67	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_O = 20 $\mu A;V_{CC}$ = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.33 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		$I_{O} = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.39	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.36	V
		$I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.50	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.50	V
I _I	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.75	μA
I _{OZ}	OFF-state output current		-	-	±0.75	μ A
I _{OFF}	power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.75	μA
ΔI_{OFF}	additional power-off leakage current	$ V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}; $	-	-	±0.75	μA
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 0.8 \ V \ to \ 3.6 \ V \end{array}$	-	-	1.4	μA
ΔI_{CC}	additional supply current		<u>[1]</u> -	-	75	μA

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

[1] One input at V_{CC} – 0.6 V, other input at V_{CC} or GND.

Low-power D-type transparent latch; 3-state

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 11.

Symbol	Parameter	Conditions			25 °C			–40 °C t	to +125 °C	;	Unit
				Min	Typ[1]	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
C _L = 5 p	F										
t _{pd}	propagation	D to Q; see Figure 7	[2]								
	delay	$V_{CC} = 0.8 V$		-	21.4	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V} \text{ to } 1.3 \text{ V}$		2.8	6.6	13.5	2.6	13.8	2.6	15.2	ns
		$V_{CC} = 1.4 V$ to 1.6 V		2.4	4.6	7.8	2.1	8.3	2.1	9.1	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		1.9	3.7	6.2	1.6	6.7	1.6	7.3	ns
		V_{CC} = 2.3 V to 2.7 V		1.8	2.9	4.1	1.5	4.5	1.5	4.9	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.5	2.5	3.5	1.2	4.0	1.2	4.5	ns
		LE to Q; see Figure 8	[2]								
		$V_{CC} = 0.8 V$		-	20.3	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V		2.7	6.2	13.6	2.5	14.0	2.5	15.4	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.3	4.4	7.6	2.0	8.5	2.0	9.3	ns
		V _{CC} = 1.65 V to 1.95 V		1.8	3.5	5.8	1.5	6.7	1.5	7.3	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		1.5	2.6	4.0	1.3	4.4	1.3	4.8	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.3	2.2	3.3	1.1	3.8	1.1	4.2	ns
t _{en}	enable time	OE to Q; see Figure 10	[3]								
		$V_{CC} = 0.8 V$		-	17.9	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V		3.2	5.1	9.2	3.0	9.2	3.0	10.1	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.6	3.8	5.8	2.4	6.1	2.4	6.7	ns
		V _{CC} = 1.65 V to 1.95 V		2.2	3.3	4.8	2.0	5.0	2.0	5.5	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		2.0	2.7	3.8	1.8	4.0	1.8	4.4	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.9	2.5	3.4	1.8	3.6	1.8	4.0	ns
t _{dis}	disable time	OE to Q; see Figure 10	[4]								
		$V_{CC} = 0.8 V$		-	9.4	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.9	4.2	7.5	2.8	7.9	2.8	8.7	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.2	3.2	4.9	2.1	5.3	2.1	5.8	ns
		V _{CC} = 1.65 V to 1.95 V		2.2	3.0	4.4	2.1	4.9	2.1	5.4	ns
		V_{CC} = 2.3 V to 2.7 V		1.6	2.2	3.1	1.5	3.4	1.5	3.7	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.9	2.6	3.3	1.8	3.6	1.8	4.0	ns

Low-power D-type transparent latch; 3-state

Symbol	Parameter	Conditions			25 °C			–40 °C i	to +125 °C	;	Unit
				Min	Typ[1]	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
C _L = 10 p	ρF										
pd		D to Q; see Figure 7	[2]								
	delay	$V_{CC} = 0.8 V$		-	24.4	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V		3.0	7.5	15.3	2.7	15.9	2.7	17.4	ns
		$V_{CC} = 1.4 V \text{ to } 1.6 V$		2.6	5.3	9.0	2.2	9.4	2.2	10.3	ns
		V _{CC} = 1.65 V to 1.95 V		2.5	4.3	6.9	2.1	7.3	2.1	8.0	ns
		V_{CC} = 2.3 V to 2.7 V		2.0	3.5	4.8	1.8	5.3	1.8	5.9	ns
		V_{CC} = 3.0 V to 3.6 V		1.8	3.1	4.2	1.7	4.6	1.7	5.1	ns
		LE to Q; see Figure 8	[2]								
		$V_{CC} = 0.8 V$		-	23.3	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V} \text{ to } 1.3 \text{ V}$		2.9	7.1	15.4	2.7	16.1	2.7	17.7	ns
		$V_{CC} = 1.4 V \text{ to } 1.6 V$		2.5	5.0	8.8	2.1	9.5	2.1	10.4	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.3	4.1	6.6	2.0	7.3	2.0	8.1	ns
		V_{CC} = 2.3 V to 2.7 V		1.9	3.1	4.7	1.6	5.2	1.6	5.8	ns
		V_{CC} = 3.0 V to 3.6 V		1.7	2.8	4.0	1.4	4.4	1.4	4.9	ns
en	enable time	OE to Q; see Figure 10	[3]								
		$V_{CC} = 0.8 V$		-	21.2	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V} \text{ to } 1.3 \text{ V}$		3.7	6.0	10.6	3.4	10.6	3.4	11.7	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		3.1	4.5	6.7	2.8	7.0	2.8	7.7	ns
		V _{CC} = 1.65 V to 1.95 V		2.7	3.9	5.5	2.5	5.8	2.5	6.4	ns
		V_{CC} = 2.3 V to 2.7 V		2.4	3.3	4.5	2.2	4.7	2.2	5.2	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.3	3.1	4.1	2.2	4.3	2.2	4.7	ns
dis	disable time	OE to Q; see Figure 10	[4]								
		$V_{CC} = 0.8 V$		-	11.3	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.9	5.3	8.7	3.8	9.2	3.8	10.1	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		3.0	4.1	5.8	2.9	6.2	2.9	6.8	ns
		V _{CC} = 1.65 V to 1.95 V		3.2	4.2	5.7	3.1	6.0	3.1	6.6	ns
		V_{CC} = 2.3 V to 2.7 V		2.3	3.0	4.0	2.2	4.3	2.2	4.7	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		3.0	3.8	4.7	2.9	5.0	2.9	5.5	ns

Table 8. Dynamic characteristics ...continued

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Low-power D-type transparent latch; 3-state

Symbol	Parameter	Conditions			25 °C			−40 °C 1	to +125 °C	;	Uni
				Min	Typ <mark>[1]</mark>	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
C _L = 15 p	ρF										
pd		D to Q; see Figure 7	[2]								
	delay	$V_{CC} = 0.8 V$		-	27.3	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V		3.5	8.3	16.9	3.2	17.5	3.2	19.2	ns
		$V_{CC} = 1.4 V$ to 1.6 V		3.1	5.9	9.6	2.7	10.5	2.7	11.6	ns
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		2.6	4.8	7.6	2.2	8.5	2.2	9.3	ns
		V_{CC} = 2.3 V to 2.7 V		2.5	3.9	5.5	2.2	5.9	2.2	6.5	ns
		$V_{CC} = 3.0 V \text{ to } 3.6 V$		2.2	3.6	4.9	1.8	5.5	1.8	6.0	ns
		LE to Q; see Figure 8	[2]								
		$V_{CC} = 0.8 V$		-	26.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.3	7.9	17.3	3.0	18.0	3.0	19.8	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		3.0	5.6	9.7	2.5	10.7	2.5	11.8	ns
		V _{CC} = 1.65 V to 1.95 V		2.5	4.6	7.4	2.2	8.3	2.2	9.1	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		2.3	3.6	5.3	2.0	5.9	2.0	6.4	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.1	3.2	4.6	1.8	5.1	1.8	5.6	ns
en	enable time	OE to Q; see Figure 10	[3]								
		$V_{CC} = 0.8 V$		-	24.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		4.1	6.8	12.1	3.8	12.1	3.8	13.3	ns
		V _{CC} = 1.4 V to 1.6 V		3.5	5.1	7.5	3.2	7.9	3.2	8.7	ns
		V _{CC} = 1.65 V to 1.95 V		3.1	4.4	6.1	2.8	6.5	2.8	7.2	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		2.8	3.7	5.0	2.5	5.3	2.5	5.8	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.6	3.5	4.7	2.5	4.9	2.5	5.4	ns
dis	disable time	OE to Q; see Figure 10	[4]								
		$V_{CC} = 0.8 V$		-	13.1	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.9	6.5	9.8	4.8	10.4	4.8	11.4	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		3.9	5.0	6.8	3.8	7.3	3.8	8.0	ns
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		4.2	5.3	6.9	4.1	7.3	4.1	8.0	ns
		V_{CC} = 2.3 V to 2.7 V		3.0	3.8	4.8	2.9	5.1	2.9	5.6	ns
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V		4.1	5.0	6.1	4.0	6.4	4.0	7.0	ns

Table 8. Dynamic characteristics ...continued

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Low-power D-type transparent latch; 3-state

Symbol	Parameter	Conditions		25 °C			–40 °C to +125 °C		;	Unit
			Mir	n Typ <mark>[1]</mark>	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
C _L = 30 p	ρF					. ,	. ,	. ,	. ,	
t _{pd}	propagation	D to Q; see Figure 7	2]							
P.4	delay	$V_{CC} = 0.8 V$	-	35.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	10.6	22.1	3.7	23.3	3.7	25.6	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V	3.6	7.5	12.3	3.5	13.6	3.5	15.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.5	6.2	9.5	3.2	10.5	3.2	11.5	ns
		V _{CC} = 2.3 V to 2.7 V	3.3	5.1	6.9	2.9	7.6	2.9	8.3	ns
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V	3.0	4.7	6.4	2.9	7.2	2.9	7.9	ns
		LE to Q; see Figure 8	2]							
		$V_{CC} = 0.8 V$	-	34.8	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.9	10.2	22.2	3.7	23.5	3.7	25.9	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V	3.5	7.2	12.4	3.4	13.7	3.4	15.1	ns
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$	3.3	5.9	9.5	3.0	10.5	3.0	11.6	ns
		V_{CC} = 2.3 V to 2.7 V	3.1	4.8	6.8	2.7	7.5	2.7	8.2	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.9	4.4	6.1	2.6	7.0	2.6	7.7	ns
en	enable time	OE to Q; see Figure 10	3]							
		$V_{CC} = 0.8 V$	-	34.5	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	5.5	9.1	16.2	4.9	16.2	4.9	17.8	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V	4.6	6.7	9.9	4.2	10.5	4.2	11.6	ns
		V _{CC} = 1.65 V to 1.95 V	4.2	5.7	7.9	3.7	8.6	3.7	9.5	ns
		V_{CC} = 2.3 V to 2.7 V	3.6	4.9	6.4	3.4	6.9	3.4	7.6	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	3.4	4.7	6.1	3.3	6.5	3.3	7.2	ns
dis	disable time	OE to Q; see Figure 10	4]							
		$V_{CC} = 0.8 V$	-	19.2	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	8.0	9.9	13.7	7.9	14.5	7.9	16.0	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V	6.3	7.7	9.7	6.2	10.5	6.2	11.6	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V	7.3	8.7	10.6	7.2	11.3	7.2	12.4	ns
		V_{CC} = 2.3 V to 2.7 V	5.2	6.2	7.5	5.1	7.8	5.1	8.6	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	7.5	8.8	10.2	7.4	10.5	7.4	11.6	ns
C _L = 5 pl	F, 10 pF, 15 pl	F and 30 pF								
W	pulse width	LE HIGH; see Figure 8								
		$V_{CC} = 0.8 V$	-	4.0	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V	-	0.7	-	2.1	-	2.1	-	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V	-	0.5	-	1.3	-	1.3	-	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V	-	0.4	-	1.0	-	1.0	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	0.3	-	0.8	-	0.8	-	ns
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V	-	0.2	-	0.8	-	0.8	-	ns

Table 8. Dynamic characteristics ... continued

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Low-power D-type transparent latch; 3-state

Symbol	Parameter	Conditions		25 °C			–40 °C to +125 °C			Unit
			Min	Typ <mark>[1]</mark>	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
t _{su(H)}	set-up time HIGH	D to LE; see Figure 9								
		$V_{CC} = 0.8 V$	-	4.6	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V	-	0.9	-	2.2	-	2.2	-	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V	-	0.6	-	1.4	-	1.4	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.4	-	1.0	-	1.0	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	0	-	0.6	-	0.6	-	ns
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V	-	-0.1	-	0.4	-	0.4	-	ns
t _{su(L)}	set-up time LOW	D to LE; see Figure 9								
		$V_{CC} = 0.8 V$	-	4.0	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V	-	1.2	-	2.7	-	2.7	-	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V	-	0.7	-	1.5	-	1.5	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.6	-	1.2	-	1.2	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	0.4	-	0.9	-	0.9	-	ns
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V	-	0.3	-	0.7	-	0.7	-	ns
t _h	hold time	D to LE HIGH or LOW; see <u>Figure 9</u>								
		$V_{CC} = 0.8 V$	-	-4.6	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V	-	-0.9	-	-0.1	-	-0.1	-	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V	-	-0.6	-	-0.1	-	-0.1	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.4	-	0	-	0	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	-0.2	-	0.2	-	0.2	-	ns
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V	-	-0.1	-	0.3	-	0.3	-	ns

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 11.

Low-power D-type transparent latch; 3-state

Symbol	Parameter	Conditions		25 °C		–40 °C to +125 °C				Unit
				Typ[1]	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
1 D	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [5][6]	<u>9</u>							
		output enabled								
		$V_{CC} = 0.8 V$	-	2.0	-	-	-	-	-	pF
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	-	2.0	-	-	-	-	-	pF
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V	-	2.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	2.1	-	-	-	-	-	pF
		V_{CC} = 2.3 V to 2.7 V	-	2.4	-	-	-	-	-	pF
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	2.8	-	-	-	-	-	рF

Table 8. Dynamic characteristics ... continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 11.

[1] All typical values are measured at nominal V_{CC} .

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] t_{en} is the same as t_{PZH} and t_{PZL} .

[4] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

[5] All specified values are the average typical values over all stated loads.

[6] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma(C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

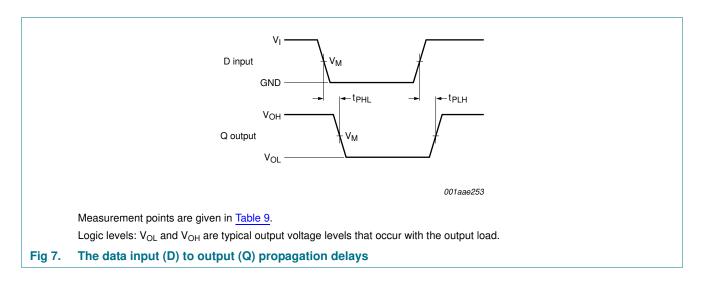
C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs;

N = number of inputs switching.

12. Waveforms



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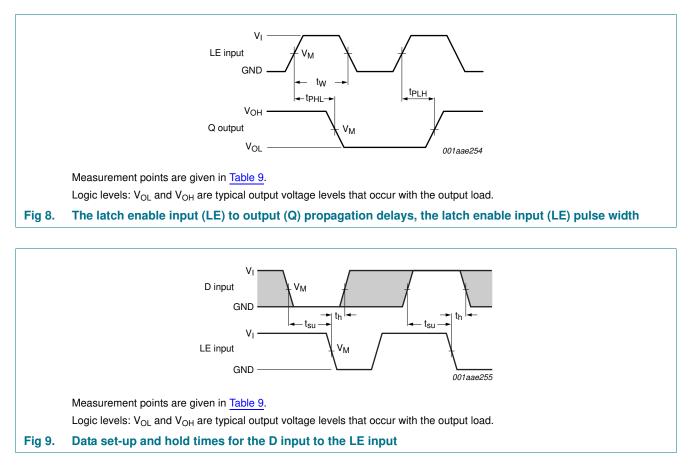


Table 9. Measurement points

Supply voltage Output		Input				
V _{cc}	V _M	V _M	VI	t _r = t _f		
0.8 V to 3.6 V	$0.5 imes V_{CC}$	$0.5 imes V_{CC}$	V _{CC}	≤ 3.0 ns		

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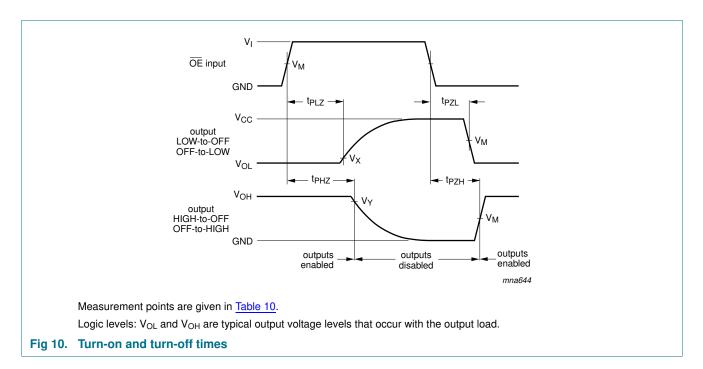


Table 10. Measurement points

Supply voltage	Input	Output	Output				
V _{CC}	V _M	V _M	V _X	Vy			
0.8 V to 1.6 V	$0.5 imes V_{CC}$	$0.5 imes V_{CC}$	V _{OL} + 0.1 V	V _{OH} – 0.1 V			
1.65 V to 2.7 V	$0.5\times V_{CC}$	$0.5 \times V_{CC}$	V _{OL} + 0.15 V	V _{OH} – 0.15 V			
3.0 V to 3.6 V	$0.5\times V_{CC}$	$0.5 \times V_{CC}$	V _{OL} + 0.3 V	$V_{OH} - 0.3 \ V$			

Low-power D-type transparent latch; 3-state

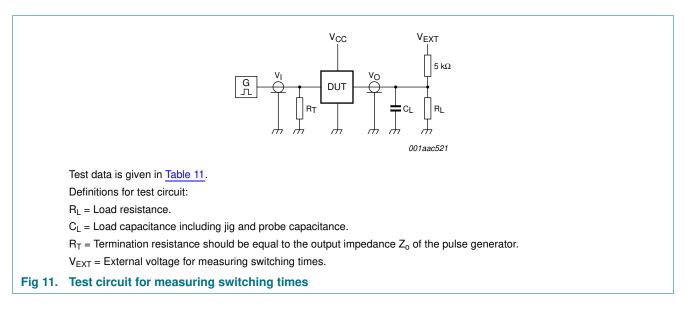


Table 11. Test data

Supply voltage	Load	V _{EXT}			
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$, for measuring propagation delays, setup and hold times and pulse width $R_L = 1 M\Omega$.

Low-power D-type transparent latch; 3-state

13. Package outline

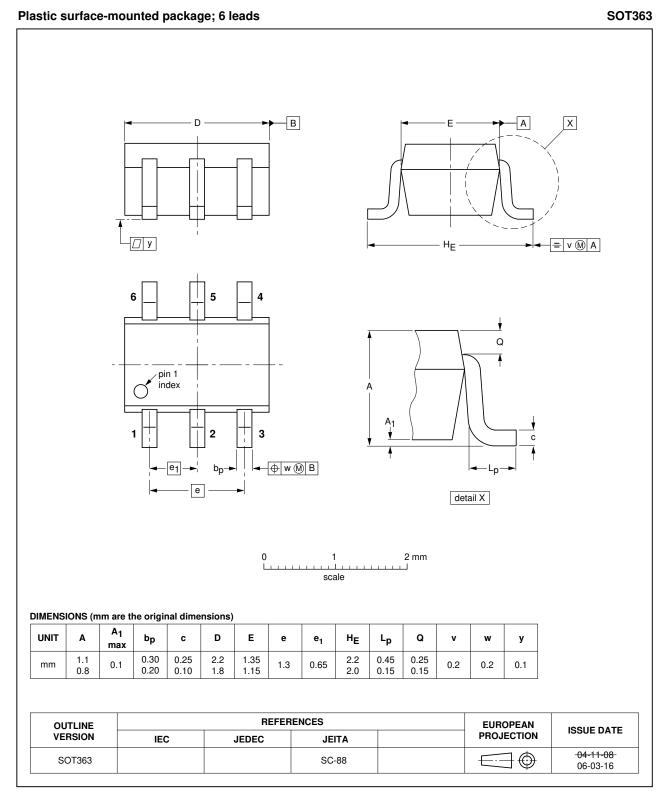


Fig 12. Package outline SOT363 (SC-88)

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Low-power D-type transparent latch; 3-state

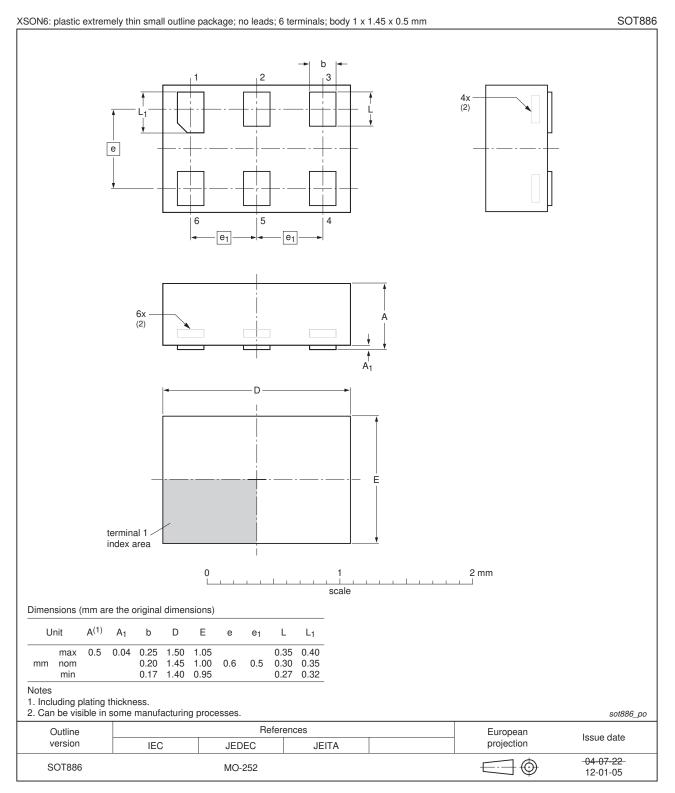


Fig 13. Package outline SOT886 (XSON6)

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Low-power D-type transparent latch; 3-state

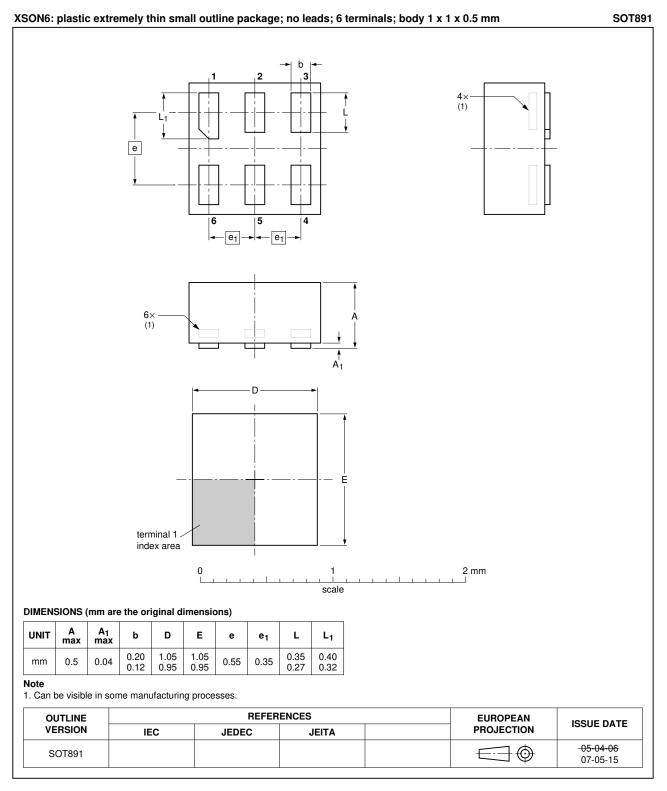
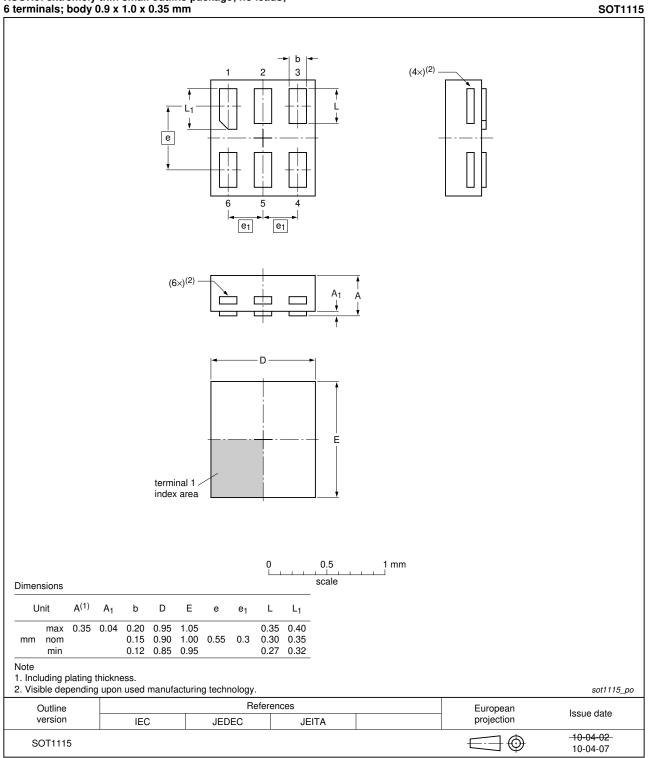


Fig 14. Package outline SOT891 (XSON6)

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Low-power D-type transparent latch; 3-state

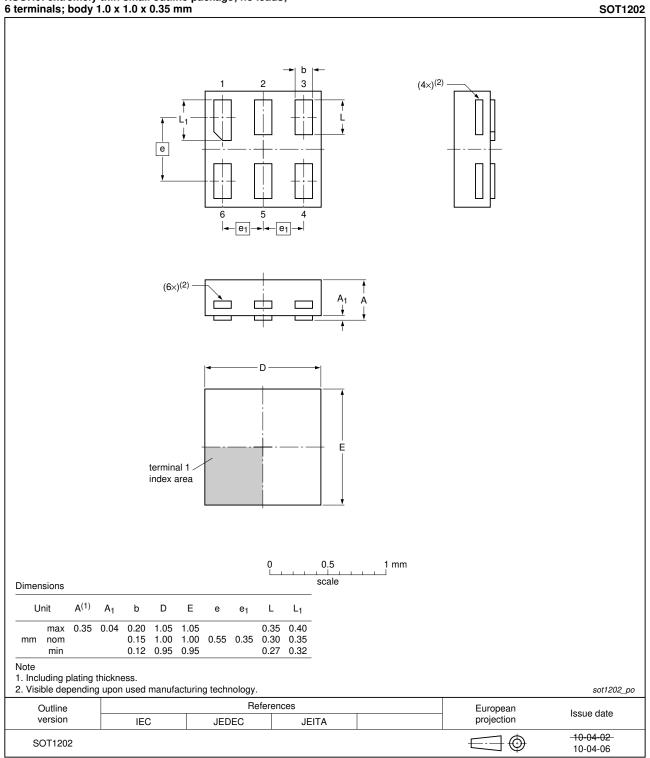


XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

Fig 15. Package outline SOT1115 (XSON6)

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XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 16. Package outline SOT1202 (XSON6)

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14. Abbreviations

Table 12. Al	bbreviations
Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

15. Revision history

Table 13. Revision history **Document ID Release date** Data sheet status Change notice Supersedes 74AUP1G373 v.6 20120704 Product data sheet 74AUP1G373 v.5 Modifications: • Package outline drawing of SOT886 (Figure 13) modified. 74AUP1G373 v.5 20111125 Product data sheet 74AUP1G373 v.4 -Modifications: · Legal pages updated. 74AUP1G373 v.4 20100715 Product data sheet 74AUP1G373 v.3 _ 74AUP1G373 v.3 20080109 Product data sheet 74AUP1G373 v.2 _ 74AUP1G373 v.2 20070720 Product data sheet 74AUP1G373 v.1 _ 74AUP1G373 v.1 20061129 Product data sheet --

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16. Legal information

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Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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